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\*\* CONTINUING DATA \*\*\*\*\*

*UAC*

\*\* FOREIGN APPLICATIONS \*\*\*\*\*

REPUBLIC OF KOREA 10-2003-0029073 05/07/2003 *JD*

IF REQUIRED, FOREIGN FILING LICENSE GRANTED

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Foreign Priority claimed 35 USC 119 (a-d) conditions met Verified and Acknowledged	<input checked="" type="checkbox"/> yes <input type="checkbox"/> no <input checked="" type="checkbox"/> yes <input type="checkbox"/> no <input type="checkbox"/> Met after Allowance <i>[Signature]</i> Examiner's Signature Initials	STATE OR COUNTRY KOREA, REPUBLIC OF	SHEETS DRAWING 7	TOTAL CLAIMS 17	INDEPENDENT CLAIMS 5
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21839  
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TITLE

Thin film electrode for forming ohmic contact in light emitting diodes and laser diodes using nickel-based solid solution for manufacturing high performance gallium nitride-based optical devices, and method for fabricating the same

	<input type="checkbox"/> All Fees <input type="checkbox"/> 1.16 Fees ( Filing )
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